

SI4210DY-T1-GE3

SI4210DY-T1-GE3 Information

www.pelsener.com	 SI4210DY-T1-GE3 Vishay Siliconix Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays MOSFET 2N-CH 30V 6.5A 8-SOIC 8-SOIC (0.154", 3.90mm Width) For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SI4210DY-T1-GE3 Specifications

Manufacturer Part Number	SI4210DY-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	8-SOIC (0.154", 3.90mm Width)
Series	TrenchFET?
FET Type	2 N-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	6.5A
Rds On (Max) @ Id, Vgs	35.5 mOhm @ 5A, 10V
Vgs(th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	445pF @ 15V
Power - Max	2.7W
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package	8-SO
	Report errors?

SI4210DY-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SI4210DY-T1-GE3 Payment Methods



SI4210DY-T1-GE3 Shipping Methods



If you have any question about SI4210DY-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com